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Vishay Semiconductors

COMPLIANT

HALOGEN

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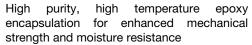
High Performance Schottky Rectifier, 8 A

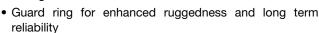


| PRIMARY CHARACTERISTICS | | | | | | | | |
|----------------------------------|-------------------------------|--|--|--|--|--|--|--|
| I _{F(AV)} | 8 A | | | | | | | |
| V _R | 80 V, 100 V | | | | | | | |
| V _F at I _F | 0.58 V | | | | | | | |
| I _{RM} | 7 mA at 125 °C | | | | | | | |
| T _J max. | 175 °C | | | | | | | |
| E _{AS} | 7.5 mJ | | | | | | | |
| Package | D ² PAK (TO-263AB) | | | | | | | |
| Circuit configuration | Single | | | | | | | |

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- · High frequency operation





- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-8TQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | | |
|-----------------------------------|---|-------------|-------|--|--|--|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | | | | |
| I _{F(AV)} | Rectangular waveform | 8 | A | | | | | |
| V _{RRM} | Range | 80/100 | V | | | | | |
| I _{FSM} | t _p = 5 μs sine | 850 | A | | | | | |
| V _F | 8 A _{pk} , T _J = 125 °C | 0.58 | V | | | | | |
| TJ | Range | -55 to +175 | °C | | | | | |

| VOLTAGE RATINGS | | | | |
|--------------------------------------|-----------|---------------|---------------|-------|
| PARAMETER | SYMBOL | VS-8TQ080S-M3 | VS-8TQ100S-M3 | UNITS |
| Maximum DC reverse voltage | V_R | - 80 | 100 | V |
| Maximum working peak reverse voltage | V_{RWM} | 00 | 100 | V |

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | |
|--|--------------------|---|---|-------|----|--|--|--|
| PARAMETER | SYMBOL | TEST COND | VALUES | UNITS | | | | |
| Maximum average forward current See fig. 5 | I _{F(AV)} | 50 % duty cycle at T _C = 157 °C, rectangular waveform | | 8 | Α | | | |
| Maximum peak one cycle | | 5 μs sine or 3 μs rect. pulse | Following any rated load | 850 | | | | |
| non-repetitive surge current See fig. 7 | I _{FSM} | 10 ms sine or 6 ms rect. pulse | condition and with rated V _{RRM} applied | 230 | Α | | | |
| Non-repetitive avalanche energy | E _{AS} | T _J = 25 °C, I _{AS} = 0.50 A, L = 60 mH | | 7.50 | mJ | | | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical | | 0.50 | А | | | |



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| ELECTRICAL SPECIFICATIONS | | | | | | | | |
|--|--------------------------------|--|---------------------------------------|-------|------|--|--|--|
| PARAMETER | SYMBOL | TEST CO | VALUES | UNITS | | | | |
| | | 8 A | T _{.1} = 25 °C | 0.72 | | | | |
| Maximum forward voltage drop See fig. 1 | V _{FM} ⁽¹⁾ | 16 A | 1j=25 C | 0.88 | V | | | |
| | V FM (1) | 8 A | T _{.1} = 125 °C | 0.58 | V | | | |
| | | 16 A | 1] = 123 0 | 0.69 | | | | |
| Maximum reverse leakage current | I _{RM} ⁽¹⁾ | T _J = 25 °C | V _R = Rated V _R | 0.55 | mA | | | |
| See fig. 2 | IRM (1) | T _J = 125 °C | VR = nateu VR | 7 | IIIA | | | |
| Maximum junction capacitance | C _T | V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz), 25 °C | | 500 | pF | | | |
| Typical series inductance | L _S | Measured lead to lead 5 m | 8 | nH | | | | |
| Maximum voltage rate of change | dV/dt | Rated V _R | 10 000 | V/µs | | | | |

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | |
|--|---------|-----------------------------------|--|-------------|----------|--|--|--|
| PARAMETER | | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | |
| Maximum junction and storage temperature range | | T _J , T _{Stg} | | -55 to +175 | °C | | | |
| Maximum thermal resistance, junction to case | | R _{thJC} | DC operation See fig. 4 | 2.0 | °C/W | | | |
| Typical thermal resistance, case to heatsink | | R _{thCS} | Mounting surface, smooth, and greased | 0.50 | | | | |
| Annyayimata waisht | | | | 2 | g | | | |
| Approximate weight | | | | 0.07 | oz. | | | |
| Manustinantanan | minimum | | | 6 (5) | kgf · cm | | | |
| Mounting torque | maximum | | | 12 (10) | (lbf·in) | | | |
| Marking device | | | Consistua D2DAK (TO 262AB) | 8TQ | 080S | | | |
| | | | Case style D ² PAK (TO-263AB) | 8TQ | 8TQ100S | | | |

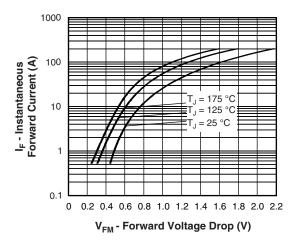


Fig. 1 - Maximum Forward Voltage Drop Characteristics

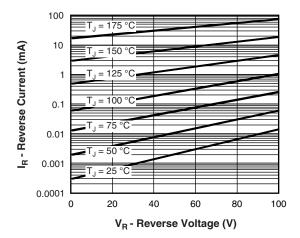


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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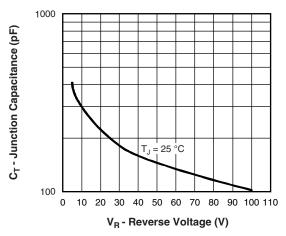


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

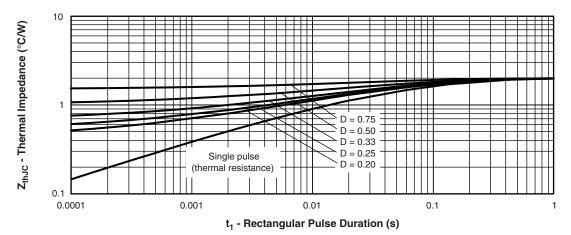


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

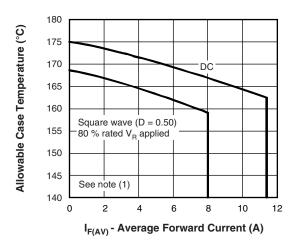


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

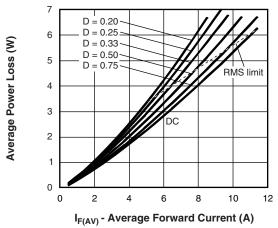
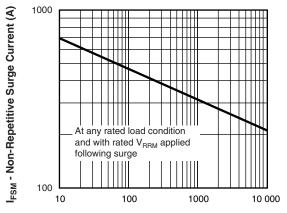


Fig. 6 - Forward Power Loss Characteristics

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t_p - Square Wave Pulse Duration (μs)

Fig. 7 - Maximum Non-Repetitive Surge Current

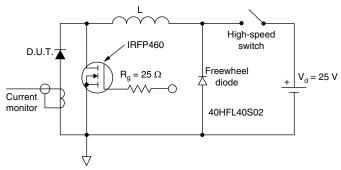
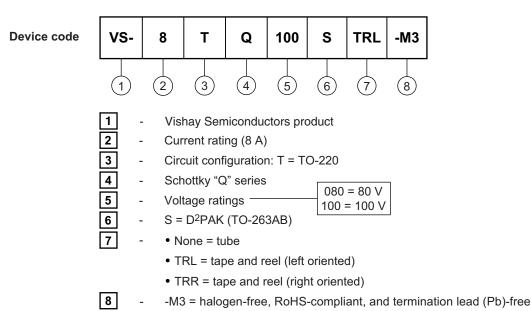


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

ORDERING INFORMATION TABLE





VS-8TQ080S-M3, VS-8TQ100S-M3

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| ORDERING INFORMATION | | | | | | | | | |
|----------------------|------------------|------------------------|--------------------------|--|--|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | | | |
| VS-8TQ080S-M3 | 50 | 1000 | Antistatic plastic tubes | | | | | | |
| VS-8TQ080STRR-M3 | 800 | 800 | 13" diameter reel | | | | | | |
| VS-8TQ080STRL-M3 | 800 | 800 | 13" diameter reel | | | | | | |
| VS-8TQ100S-M3 | 50 | 1000 | Antistatic plastic tubes | | | | | | |
| VS-8TQ100STRR-M3 | 800 | 800 | 13" diameter reel | | | | | | |
| VS-8TQ100STRL-M3 | 800 | 800 | 13" diameter reel | | | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|----------------------------|--------------------------|--|--|--|--|
| Dimensions | www.vishay.com/doc?96164 | | | | |
| Part marking information | www.vishay.com/doc?95444 | | | | |
| Packaging information | www.vishay.com/doc?96424 | | | | |
| SPICE model | www.vishay.com/doc?96227 | | | | |



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D²PAK

DIMENSIONS in millimeters and inches



| SYMBOL | MILLIM | MILLIMETERS | | INCHES | | NOTES S | SYMBOL | MILLIM | ETERS | INC | HES | NOTES |
|----------|--------|-------------|-------|--------|-------|---------|---------|--------|-------|-------|-------|-------|
| STIVIBUL | MIN. | MAX. | MIN. | MAX. | NOIES | NOTES | STWIDOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.06 | 4.83 | 0.160 | 0.190 | | | D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | | | Е | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | | E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 | | е | 2.54 | BSC | 0.100 |) BSC | |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | | | Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | | L | 1.78 | 2.79 | 0.070 | 0.110 | |
| С | 0.38 | 0.74 | 0.015 | 0.029 | | | L1 | - | 1.65 | - | 0.066 | 3 |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 | | L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | | | L3 | 0.25 | BSC | 0.010 | BSC | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 | | L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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